

# Intel<sup>®</sup> Server Board S5000PHB

**Tested Memory Report** 

Revision 1.8 August 2008

## **Revision History**

Date	Rev	Modifications
August 2006	0.5	Preliminary Release
December 2006	1.0	Updated with tested memory for the IP Network Server NSW1U
October 10, 2007	1.1	Updated list of tested memory for the IP Network Server NSW1U
October 15, 2007	1.2	Updated list of tested memory from CMTL update
November 06, 2007	1.3	Updated list from CMTL update. Added entries for 1 GB and 2 GB modules.
January 09, 2008	1.4	Updated list from CMTL update. Added entries for 512 MB and 4 GB modules
February 05, 2008	1.5	Updated list from CMTL update. Added entry for 4 GB module
March 04, 2008	1.6	Updated list from CMTL update. Added entries for 1 GB, 2 GB, and 4 GB modules
June 27, 2008	1.7	Updated list from CMTL update. Added entries for 512 MB, 1 GB, 2 GB, and 4 GB modules
August 19, 2008	1.8	Added entry for 8 GB module

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The Intel<sup>®</sup> Server Board S5000PHB may contain design defects or errors known as errata which may cause the product to deviate from published specifications. Current characterized errata are available on request.

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**Please Note:** DIMM devices with gold contacts should NOT be placed into DIMM sockets with tin-lead contacts or vice-versa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each Rank on the memory module. Mixing of dissimilar memory is NOT recommended.

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## 1. Overview of Memory Testing

The following test processes are used to qualify Dual In-Line Memory Modules (DIMMs) for use with the Intel<sup>®</sup> Server Board S5000PHB. Memory is a vital subsystem in a server. Intel requires that strict guidelines be met before a DIMM vendor is added to the Tested Memory Report. To be included on the list as a fully supported DIMM, the memory must undergo rigorous tests to ensure that the product will perform the intended server product functions. Memory qualification for the Intel server products is performed both by Intel's Memory Validation Lab (MVL).

The Tested Memory Lists for Intel's server board products categorize memory modules as Advanced Tested. The Advanced Testing process includes a standard paper qualification and then is followed by two levels of functional testing. DIMMs that have completed memory testing are considered to be compatible with the product on which they were tested, and with the test software and operating systems thatwere used during the test process.

**Note**: Memory qualification for main memory is done by testing identical memory modules in all DIMM slots. Memory qualification does not include testing of mixed DIMM type and/or vendors. Mixing of DIMM types and/or vendors is not recommended.

## 1.1 Paper Qualification

A paper qualification is performed to verify that the specifications of a given DIMM meet Intel's memory specifications for a given product. Specification criteria reviewed include: critical timings, electrical characteristics, timing requirements, environmental requirements, and packaging requirements.

## **1.2 Functional Testing**

After a given DIMM passes the standard paper qualification, functionality of the DIMM is then tested with the intended Intel product. Two levels of functional testing are performed; Standard and Advanced.

Standard functional testing requires that the given DIMM and Intel product combination operate with no failures for a period of no less than 6 hours for both minimum and maximum DIMM configurations. Testing is performed using a Microsoft Windows\* operating system and a custom test package. The test systems operate with standard voltage and at room temperature.

## 1.3 Advanced Functional Testing

Advanced functional testing requires that the given DIMM and Intel product combination operate with no failures for a period of no less than 6 hours for both minimum and maximum DIMM configurations. Testing is performed with multiple operating systems and various custom test packages. Each test configuration is tested with high and low voltage and temperature margin conditions.

### 1.4 Computer Memory Test Lab\*

Computer Memory Test Lab, also known as "CMTL\*" is a leading memory test organization responsible for testing a broad range of memory products. A memory productthat receives a "PASS" after being tested by CMTL means it functions correctly and consumers can use the product to perform the intended server functions. In order to pass these stringent standards, memory products must maintain the highest manufacturing procedures and pass an exacting battery of tests. Testing is performed with Intel-supplied equipment and procedures defined by Intel's various functional testing levels.

#### **CMTL\*** Contact Information:

Office: (949) 716-8690 Main Fax: (949) 716-8691 Computer Memory Test Lab (CMTL) 24 Hammond Suite F Irvine, CA 92618 http://www.cmtlabs.com/

## 2. S5000PHB Memory Subsystem

The Intel<sup>®</sup> Server Board S5000PHB main memory subsystem is designed to support Fully Buffered Dual In-line (FBD) Registered DDR2-533 and DDR2-667 FBDIMM memory ECC Synchronous Dynamic Random Access Memory (SDRAM). Other industry naming conventions for DDR2-533 include PC2-4200 and for DDR2-667 include PC2-5300.

The maximum main memory capacity supported is based on the number of DIMM slots provided and maximum supported memory loads by the chipset. On the Intel<sup>®</sup> Server Board S5000PHB the maximum supported capacity is 24 GB; the minimum supported capacity is 512 MB with one single 512 MB DIMM.

Supported FBDIMM capacities for main memory include: 512 MB, 1 GB, 2 GB, and 4 GB.

## 2.1 Main Memory Population

The Intel<sup>®</sup> Server Board S5000PHB has six DIMM slots grouped into two channels for main memory. DIMMs within each bank should be identical (same manufacturer, CAS latency, number of rows, columns and devices, timing parameters etc.). Although DIMMs within a bank must be identical, the BIOS supports various DIMM sizes and configurations, which allows memory between banks to be different. Memory sizing and configuration are guaranteed only for qualified DIMMs approved by Intel.

DIMM population rules depend on the operating mode of the memory controller, which is determined by the number of DIMMs installed. DIMMs must be populated in pairs. DIMM pairs are populated in the following DIMM slot order: A1 and B1, A2 and B2, A3 and B3. DIMMs within a given pair must be identical with respect to size, speed, and organization. However, DIMM capacities can be different between different DIMM pairs.

For example, a valid mixed DIMM configuration may have 512 MB DIMMs installed in DIMM Slots A1 and B1, and 1 GB DIMMs installed in DIMM slots A2 and B2.



#### 2.1.1 Memory Subsystem

The MCH masters two fully buffered DIMM (FBD) memory channels. FBD memory utilizes a narrow highspeed frame-oriented interface referred to as a channel. On the server board, the two channels are routed to six DIMM slots and are capable of supporting registered DDR2-533 and DDR2-667 FBDIMM memory.

**Note**: Only fully buffered DDR2 DIMMs are supported on this server board.

The following table lists the current supported memory types.

	FBDIMN	1-533 CL	4 & FBD	IMM-667 CL	5 Memory Ma	trix
DIMM Capacity	DIMM Organization	SDRAM Density	SDRAM Organization	# SDRAM Devices	# Address bits Row/Bank/Column	# of Ranks
512MB	64M x72	512Mbit	64M x 8	9	14/10/2	1
1GB	128M x 72	512Mbit	64M x 8	18	14/10/2	2
1GB	128M x 72	512Mbit	128M x 4	18	14/11/2	1
1GB	128M x 72	512Mbit	128M x 8	9	14/10/3	1
2GB	256M x72	512Mbit	128M x 4	36	14/11/2	2
2GB	256M x72	1Gbit	256M x 4	18	14/11/3	1
2GB	256M x72	1Gbit	128M x 8	18	14/10/3	2
4GB	512M x72	1Gbit	256M x 4	36	14/11/3	2
4GB	512M x 72	2Gbit	512M x 4	18	13/11/2	2

## 3. S5000PHB Main Memory Tested on the IP Network Server NSW1U

The following tables list DIMM devices tested as compatible with the Intel<sup>®</sup> Server Board S5000PHB on the IP Network Server NSW1U. The list of tested memory is periodically updated when qualified memory is added during the production life of the Intel product.

Intel strongly recommends the use of ECC memory in all server products.

Memory modules not listed in the following tables have not been tested for compatibility and their use with the Intel<sup>®</sup> Server Board S5000PHB may result in unpredictable operation and data loss.

**Caution**: Third party memory vendors may use the same module part number with different DRAM vendors and die revisions. To ensure proper system operation, verify that each DRAM vendor and die revision has been separately tested and qualified. Please notify CMTL if there is a discrepancy. This list is subject to change without notice.

**Note**: This list is not intended to be all-inclusive. It is provided as a convenience to Intel's general customer base, but Intel does not make any representations or warranties whatsoever regarding the quality, reliability, functionality, or compatibility of these memory modules.

	Intel <sup>®</sup> Server Board S5000PHB											
	Fully Buffe	ered ECC, DDR	2-667, C	AS Late	ncy 5, I	_ead Fre	ee DIMM	Modules				
			512 MB	Sizes (6-	4Mx72)							
Manufacturer	Part Number	DRAM Part	DRAM	PCB Part	AMB	AMB	Heat-sink	DRAM	Rank	Date		
		Number	Vendor	Number	Vendor	Revision	Vendor	Organization				
_		HY5PS12821CFP-Y5		40053A rev			_			25-		
Dataram	DTM65506C	rev C	Hynix	В	Intel	D1	Foxconn	64M x 8		Apr-07		
		KAT510920E 70E6								07- Mov		
ATP Electronics	6S	rev F	Samsung	D2F18A na	NEC	B5	Foxconn	64M x 8		07		
	00	TOVE	Carnoung	DZI TO/(TIQ	NEO	50	1 0000111	0-111 X 0		25-		
	KVR667D2S8F5	NT5TU64M8BE-3C		2025285-						May-		
Kingston	/512l	rev B	Nanya	002.A00 na	Intel	D1	Foxconn	64M x 8		07		
	KVR667D2S8F5	E5108AGBG-6E-E		2025285-			_			25-		
Kingston	/5121	rev G	Elpida	002.A00 na	Intel	D1	Foxconn	64M x 8		Jun-07		
Smort Modular				PG54G240						08-		
	2IRD5	3S rev B	Oimonda		пт	A1 5	Foxconn	64M x 8		Aug-		
reennoiogies	21003	30 ICV B	QIIIIOIIda	ACIEVA		A1.5	Тохсонн	04101 X 0		04-		
Smart Modular	SG647FBD6485	K4T51083QE-ZCE6		M395T655						Dec-		
Technologies	2-SEI	rev E	Samsung	3EZ0 na	Intel	D1	Samsung	64M x 8		07		
										04-		
_		HYB18T512800B2F-	<b>.</b>	40053A rev			_			Mar-		
Dataram	DTM65506F	3S rev B2	Qimonda	В	IDT	C1	Foxconn	64M x 8		08		
	MTOUTE6472EV									Z/- Mor		
Micron	-667D5D4	MT47H64M8B6-3:D	Micron	0499D	IDT	C1	FMHS	64M x 8		2008		
				0.002		•		0		27-		
Crucial	CT6472AF667.9									Mar-		
Technology	FD5D4	MT47H64M8B6-3:D	Micron	0499D	IDT	C1	FMHS	64M x 8		2008		
										31-		
Miener	M19H1F6472FY		Minner	0.4000		DC.	FMUC	C 414 ··· 0		Mar-		
WICTON	-667D5N6	MT47H64M8B6-3:D	MICTON	04990	NEC	B2+	FMHS	64M X 8		2008		
Crucial	CT6472AF667 9									Mar-		
Technology	FD5N6	MT47H64M8B6-3:D	Micron	0499C	NEC	B5+	FMHS	64M x 8		2008		
										03-		
	MT9HTF6472FY									Apr-		
Micron	-667D5E4	MT47H64M8B6-3:D	Micron	0499D	Intel	D1	FMHS	64M x 8		2008		
Ornalial	07047045007.0									03-		
Crucial	C164/2AF667.9		Mierer	04005	Intol	D1	EMUS	C 4M × P		Apr-		
rechnology	FD5E4	IVI 147 H64IVI8B6-3:D	Nicron	0499D	Intel	D1	FINITS	64IVI X 8		2008		

**Note:** Some memory modules may have thermal issues when used in a non-Intel 1U rack solution. Verifying any thermal limitations with your chassis supplier before purchasing a chassis is advised.

Intel <sup>®</sup> Server Board S5000PHB											
	Fully Buffe	ered ECC, DDR	2-667, C 1 GB Si	AS Late zes (128	ncy 5, L Mx72)	Lead Fro		Modules			
Manufacturer	Part Number	DRAM Part	DRAM	PCB Part	AMB	AMB	Heat-sink	DRAM	Rank	Date	
		Number	Vendor	Number	Vendor	Revision	Vendor	Organization			
		HYB18T512800BF3S		40053A rev						19-Apr-	
Dataram	DTM65507D	rev B	Qimonda	В	Intel	D1	Foxconn	64M x 8		07	
Micron	MT18HTF12872 FDY-667D6E4	MT47H64M8-3	Micron		Intel	GB-D1	FDHS	64M x 8		29-Jan- 07	
Smart Modular	SG1287FBD648	HY5PS12821CFP-Y5		KS-11						23-Apr-	
Technologies	52-HB	rev C	Hynix	(0646-3F)	IDT	A1.5	Hynix	64M x 8		07	
				PG58G240							
Smart Modular	SG1287FBD648	HYB18T512800BF3S	<u>.</u>	NFBUB4R	157		_			09-May-	
lechnologies	52IBD5	rev B	Qimonda	BS rev A	IDI	A1.5	Foxconn	64M x 8		07	
Determine	DTMOSECOZO	HY5PS12821CFP-Y5	L L	40053A rev	La fa l	54	<b>-</b>	0.4140		17-May-	
Dataram	D1M65507C		Hynix	В	Intel	D1	Foxconn	64M x 8		07	
Kinneten	KVR667D2D8F5	NI5TU64M8BE-3C	News	2025286-	Intel	54	<b>F</b>	C 41 4 ··· 0		06-Jun-	
Kingston			Nanya	002.A00 na	Intel	D1	Foxconn	64M X 8		07	
ATD Electronice	AP28K72S8BHE	K4151083QE-ZCE6	Somound	SP240S08	NEC	D.E.	Foyoonn	GAM y 9		19-Jun-	
ATP Electronics			Samsung	KT 11a	INEC	БЭ	Foxconn	04IVI X 0		07	
Kingston	1CI	ED106AGBG-0E-E	Eloido	2025280-	Intol	D1	Forconn	64M x 8		27-Jun-	
Venture	/101	IEV G	Elpiua	002.A00 Ha	Inter	וט	FUXCOIIII	04101 X O		07	
Tochnology										22 101	
Group	555	rov E	Sameuna	D2E28B na	IDT	A1 5		64M x 8		23-Jui- 07	
Smart Modular	SG1287EBD6/8	KAT5108300E-70E6	Samsung	M305T205		A1.5	AVC	04101 × 0		12-Sen-	
Technologies	52-SEI	rev F	Samsung	3E70 na	IDT	C1	Foxconn	64M x 8		12-36p-	
reonnoiogies	KVR667D2D8F5	HYB18T512800BE-	Cambung	2025286-		01	1 OXOOTIIT	04101 X 0		05-Oct-	
Kingston	/1GI	3S rev B	Qimonda	002 A00 na	Intel	D1	Foxconn	64M x 8		07	
rangeten	KVR667D2D8F5	HYB18T512800BF-	Quinterrada	2025286-				0 111 / 0		05-Oct-	
Kinaston	/1GI	3S rev B	Qimonda	002.A00 na	Intel	D1	Foxconn	64M x 8		07	
Avant	AVF7228B52E5	EDE5108AHSE-6E-E		50-1451-						09-Oct-	
Technology	667F0-ELHP	rev H	Elpida	01-A rev A	Qimonda	C1	Foxconn	64M x 8		07	
				PG58G240							
Smart Modular	SG1287FBD648	K4T51083QE-ZCE6		NFBUB4R						15-Oct-	
Technologies	52SEC1	rev E	Samsung	BS rev A	IDT	C1	Foxconn	64M x 8		07	
				PG58G240							
Smart Modular	SG1287FBD648	HYB18T512800BF3S		NFBUB4R						25-Oct-	
Technologies	52IBDC	rev B	Qimonda	BS rev A	IDT	C1	Foxconn	64M x 8		07	
	MT18HTF12872		Micron							04-Mar-	
Micron	FDY-667D6E4	MT47H64M8B6-3:D	MICION	0500E	Intel	D1	FMHS	64M x 8		08	
	MT18HTF12872		Micron	_			FMHS			04-Mar-	
Micron	FDY-667D6N6	MT47H64M8B6-3:D	meren	0500E	NEC	B5+		64M x 8		08	
	MT9HTF12872F		Micron				FMHS			04-Mar-	
Micron	Y-667E1D4	MT47H128M8HQ-3:E		0499D	IDT	C1		128M x 8		08	
	MT9HTF12872F		Micron				FMHS			04-Mar-	
Micron	Y-667E1N8	MT47H128M8HQ-3:E		0499D	NEC	D1-667		128M x 8		80	
Crucial	CI12872AF667.		Micron	05005		54	FMHS			04-Mar-	
Technology	18FD6E4	MT47H64M8B6-3:D	-	0500E	Intel	1U		64M x 8		08	
Urucial	10000001128/2AF66/.		Micron	05005		DE .	FIVIHS	CAM y O		04-iviar-	
		IVI 147 H04IVI8B0-3:D		0500E	NEC	B0+	EMULO	04IVI X 8		04 Мат	
Uruciai	0EE1D4		Micron	04000		C1	FINHS	12914 - 9		04-iviar-	
Crucial	9FE104	1VI 14/ 1 1201VI01Q-3.E		0499D	וטו		EMLIC			00 04 Mor	
Technology		MT47H128M8H∩_2·⊏	Micron	04000	NEC	D1-667	LINIL9	128M v 8		04-10121-	
recrimology					1	01-007			L	00	

[Continued]

Intel <sup>®</sup> Server Board S5000PHB Fully Buffered ECC, DDR2-667, CAS Latency 5, Lead Free DIMM Modules 1 GB Sizes (128Mx72)											
[Continued]											
Manufacturer	Anufacturer Part Number DRAM Part DRAM PCB Part AMB AMB Heat-sink DRAM Rank Date										
		Number	Vendor	Number	Vendor	Revision	Vendor	Organization			
		HYB18T512800B2F3		40053A rev						06-Mar-	
Dataram	DTM65507G	S rev B2	Qimonda	В	IDT	C1	Foxconn	64M x 8		08	
	MT9HTF12872F									09-May-	
Micron	Y-667E1N6	MT47H128M8HQ-3:E	Micron	0499D	NEC	B5+	FMHS	128M x 8		08	
Crucial	CT12872AF667.									09-May-	
Technology	9FE1N6	MT47H128M8HQ-3:E	Micron	0499D	NEC	B5+	FMHS	128M x 8		08	
	MT18HTF12872									09-May-	
Micron	FY-667D6D4	MT47H128M4B6-3:D	Micron	0501F	IDT	C1-667	FMHS	128M x 4		08	
Crucial	CT12872AF667.									09-May-	
Technology	18F4D6D4	MT47H128M4B6-3:D	Micron	0501F	IDT	C1-667	FMHS	128M x 4		08	
Avant	AVF7228B52E5	EDE5108AJBG-8E-E		D2F28B						30-May-	
Technology	667F1ELJP-IS	rev J	Elpida	rev B	IDT	C1	Foxconn	64M x 8		08	
Avant	AVF7228B52E5	NT5TU64M8BE-25C		D2F28B						09-Jun-	
Technology	667F1NYBP-IS	rev B	Nanya	rev B	IDT	C1	Foxconn	64M x 8		08	

**Note:** Some memory modules may have thermal issues when used in a non-Intel 1U rack solution. Verifying any thermal limitations with your chassis supplier before purchasing a chassis is advised.

Intel <sup>®</sup> Server Board S5000PHB Fully Buffered ECC, DDR2-667, CAS Latency 5, Lead Free DIMM Modules											
	T any Band		2 GB Si	zes (256	Mx72)	_00011		moduloo			
Manufacturer	Part Number	DRAM Part	DRAM	PCB Part	AMB	AMB	Heat-sink	DRAM	Rank	Date	
		Number	Vendor	Number	Vendor	Revision	Vendor	Organization			
Smart Modular	SG2567FBD284	K4T51043QC-ZCE6		M395T575						27-Apr-	
Technologies	52-SCD	rev C	Samsung	0-CZ0 na	IDT	A1.5	Samsung	128M x 4		07	
_		HYB18T512400BF3S		40060A rev		_	_			14-May-	
Dataram	DTM65508D	rev B	Qimonda	A	Intel	D1	Foxconn	128M x 4		07	
Ventura		14175404000 7050									
Technology	D2-56VF82SIV-	K4151043QC-ZCE6	<b>C</b>		IDT			400144		23-May-	
Group	555		Samsung	D2F24E na	וטו	A1.5	AVC	128IVI X 4		01	
Dataram		H15P5124210FP-15	Hypix	40060A rev	Intol	D1	Forconn	129M v 4		01-Jun-	
Dataram	K\/R667D2D8F5	MT47H128M8HO-3	TIYTIX	2025286-	IIILEI		1 OXCOULT	120101 × 4		14- lun-	
Kingston	/2GI	rev F	Micron	002 A00 na	Intel	D1	Foxconn	128M x 8		07	
Ringston	AP56K72G4BH	K4T510430E-7CE6	WICTON	SP240G04	inter		1 OXCOIIII	120101 X 0		29-Jun-	
ATP Electronics	E6S	rev E	Samsung	K1 na	NEC	B5	Foxconn	128M x 4		07	
Legacy	M527NAE90BE-	MT47H128M8HQ-3	eameang	D2F28B		20		.20.0.7.1		05-Jul-	
Electronics Inc.	30R	rev E	Micron	rev B	IDT	A1.5	AVC	128M x 8		07	
		K4T51043QE-ZCE6		48.1A205.0						06-Jul-	
Apacer	75.A72AI.G00	rev E	Samsung	11 rev 1	Intel	D1	AVC	128M x 4		07	
Legacy	B527M4C90EE-	K4T51043QC-ZCE6		D2F24E_A						10-Jul-	
Electronics Inc.	30R	rev C	Samsung	rev A	IDT	A1.5	AVC	128M x 4		07	
				PG54G240							
Smart Modular	SG2567FBD284	HYB18T512400BF3S	<u>.</u>	NFSUB1R			_			23-Jul-	
lechnologies	52IBD5	rev B	Qimonda	ES rev C	IDT	A1.5	Foxconn	128M x 4		07	
1C and the	KVR667D2D4F5	HYB181512400BF3S	0	2025372-	L. C. I	54	<b>-</b>	100111		28-Sep-	
Kingston	/2GI	rev B	Qimonda	002.A00 na	Intel	D1	Foxconn	128M X 4		07	
Smort Modulor	SC2567EDD204			PG54G240						01 Oct	
	52IBDC	rov R	Oimonda	ES rev C		C1	Forconn	128M x 4		01-001-	
reonnoiogies	KVR667D2D4F5	NT5TU128M4BE-3C	Qintonda	2025378-		01	1 0200111	12001 X 4		03-Oct-	
Kinaston	/2GI	rev B	Nanva	001.A00 na	Intel	D1	Foxconn	128M x 4		00 000	
Smart Modular	SG2567FBD284	HYB18T512405BF3S	luliju	0712 (240-						19-Oct-	
Technologies	52-IBQ	rev B	Qimonda	25-4)	Qimonda	C1	Logitex	128M x 4		07	
	KVR667D2D8F5	E1108ACBG-6E-E		2025286-						15-Feb-	
Kingston	/2GI	rev C	Elpida	002.A00 na	Intel	D1	Foxconn	128M x 8	2	08	
	MT18HTF25672									04-Mar-	
Micron	FDY-667E1D4	MT47H128M8HQ-3:E	Micron	0500E	IDT	C1	FMHS	128M x 8		08	
	MT36HTF25672									04-Mar-	
Micron	FY-667D1D4	MT47H128M4B6-3:D	Micron	0561A	IDT	C1	FMHS	128M x 8		08	
	MT18HTF25672									04-Mar-	
Micron	FY-667E1D4	MT47H256M4HQ-3:E	Micron	0501F	IDT	C1	FMHS	256M x 4		08	
Crucial	C125672AF667.		N 41 a 11 a 11	05005	IDT	0.1		40014 - 0		04-Mar-	
rechnology	18FE1D4	MT4/H128M8HQ-3:E	Micron	0500E	וטו	C1	FMHS	128M x 8		80	
Crucial	C125672AF667.	MT47U400MAD6 0.D	Mioron	05614		C1	EMUS	100M v 9		04-Mar-	
rechnology	3050104	IVI 14/ F1 1201V14D0-3.D		USOTA	יטו ז		LINUDO			00	

[Continued]

	Fully Buffe	Inte ered ECC, DDR	el <sup>®</sup> Serve 2-667, C	r Board AS Late	S5000F ncy 5, I	PHB Lead Fr	ee DIMM	Modules					
	•		2 GB Si	zes (256	Mx72)								
	[Continued]												
Manufacturer	Manufacturer Part Number DRAM Part DRAM PCB Part AMB AMB Heat-sink DRAM Rank Date												
		Number	Vendor	Number	Vendor	Revision	Vendor	Organization					
		HYB18T512400B2F3		40084A rev						11-Mar-			
Dataram	DTM65508F	S rev B2	Qimonda	A	IDT	C1	Foxconn	128M x 4		08			
	AP56K72S8BJE	K4T1G084QQ-HCE6		D2F28B						17-Apr-			
ATP Electronics	6S	rev Q	Samsung	rev B	NEC	D1	Foxconn	128M x 8		08			
	MT18HTF25672									29-Apr-			
Micron	FDY-667E2D6	MT47H128M8HQ-3:E	Micron	0658A	IDT	L4-667	FMHS	128M x 8		08			
Crucial	CT25672AF667.									29-Apr-			
Technology	18FE2D6	MT47H128M8HQ-3:E	Micron	0658A	IDT	L4-667	FMHS	128M x 8		08			
	MT18HTF25672									30-Apr-			
Micron	FDY-667E1N8	MT47H128M8HQ-3:E	Micron	0500E	NEC	D1-667	FMHS	128M x 8		08			
Crucial	CT25672AF667.			_		_				30-Apr-			
Technology	18FE1N8	MT47H128M8HQ-3:E	Micron	0500E	NEC	D1-667	FMHS	128M x 8		08			
	KVR667D2D8F5	HY5PS1G831CFP-		2025286-						07-May-			
Kingston	/2Gi	Y5 rev C	Hynix	002.A00 na	Intel	D1	Foxconn	128M x 8		08			
	KVR667D2D4F5	HYB18T512400B2F2		2025378-						11-Jun-			
Kingston	/2GI	5F rev B2	Qimonda	001.A00	INTEL	D1	Foxconn	128M x 4		08			
Avant	AVF7256B61E5	EDE1108ACBG-8E-E		D2F28B						13-Jun-			
Technology	667F1ELCP-IS	rev C	Elpida	rev B	IDT	C1	Foxconn	128M x 8		08			

**Note:** Some memory modules may have thermal issues when used in a non-Intel 1U rack solution. Verifying any thermal limitations with your chassis supplier before purchasing a chassis is advised.

	Intel <sup>®</sup> Server Board S5000PHB										
	Fully Buffe	ered ECC, DDR	2-667, C	AS Late	ncy 5, I	_ead Fr	ee DIMM	Modules			
	•	·	4 GB Si	zes (512	Mx72)						
Manufacturer	Part Number	DRAM Part	DRAM	PCB Part	AMB	AMB	Heat-sink	DRAM	Rank	Date	
		Number	Vendor	Number	Vendor	Revision	Vendor	Organization			
Legacy	M547RAE90EE-	MT47H256M4HQ-3		D2F24E						15-May-	
Electronics Inc.	30R	rev E	Micron	rev E	IDT	A1.5	AVC	256M x 4		07	
	AP12K72G4BJE	MT47H256M4HQ-3		SP240G04						21-May-	
ATP Electronics	6M	rev E	Micron	K1 na	NEC	B5	Foxconn	256M x 4		07	
	KVR667D2D4F5									21-Jun-	
Kingston	/4GI	E1108ABSH-E rev B	Elpida	0646 na	IDT	A1.5	Foxconn	256M x 4		07	
				PG54G240							
Smart Modular	SG5127FBD225	MT47H256M4HQ-3		NFSUB2R						23-Jul-	
Technologies	652MEC	rev E	Micron	ES rev A	IDT	C1	Foxconn	256M x 4		07	
		E1104ACSE-6E-E		48.1A205.0						01-Aug-	
Apacer	78.BHGA8.421	rev C	Elpida	11 rev 1	IDT	C1	AVC	256M x 4		07	
Smart Modular	SG5127FBD225	K4T1G044QC-ZCE6		M395T575						22-Aug-	
Technologies	652-SC	rev C	Samsung	0EZ0 na	IDT	A1.5	Samsung	256M x 4		07	
Smart Modular	SG5127FBD225	K4T1G044QC-ZCE6		M395T575						24-Aug-	
Technologies	652SCD	rev C	Samsung	0EZ0 na	IDT	C1	Samsung	256M x 4		07	
	AP12K72G4BJE	K4T1G044QC-ZCE6								19-Dec-	
ATP Electronics	6S	rev C	Samsung	D2F24E na	NEC	D1	Foxconn	256M x 4		07	
		HY5PS1G431CFP-		40084A						08-Jan-	
Dataram	DTM65510C	Y5 rev C	Hynix	rev A	IDT	C1	Foxconn	256M x 4		08	
	MT36HTF51272									04-Mar-	
Micron	FY-667E1D4	MT47H256M4HQ-3:E	Micron	0589A	IDT	C1	FMHS	256M x 4		08	
Crucial	CT51272AF667.									04-Mar-	
Technology	36FE1D4	MT47H256M4HQ-3:E	Micron	0589A	IDT	C1	FMHS	256M x 4		08	
	AP12K72G4BJE	K4T1G044QQ-HCE6		D2F24E						18-Mar-	
ATP Electronics	6S	rev Q	Samsung	rev E	NEC	D1	Foxconn	256M x 4		08	
	KVR667D2D4F5	E1104ACSE-6E-E		2025378-						04-Apr-	
Kingston	/4Gi	rev C	Elpida	001.A00	Intel	D1	Foxconn	256M x 4		08	
				BA2FRCU							
Avant	AVF7251B62E5	EDE1104ACSE-8E-E		3.10 rev			_			04-Jun-	
Technology	667F4ELCP-IS	rev C	Elpida	3.10	IDT	C1	Foxconn	256M x 4		08	

**Note:** Some memory modules may have thermal issues when used in a non-Intel 1U rack solution. It is advised that you verify any thermal limitations with your chassis supplier before purchasing a chassis.

	Intel <sup>®</sup> Server Board S5000PHB Fully Buffered ECC, DDR2-667, CAS Latency 5, Lead Free DIMM Modules 8 GB Sizes (1024M x 72)											
Manufacturer	Part Number	DRAM Part	DRAM	PCB Part	AMB	AMB	Heat-sink	DRAM	Rank	Date		
		Number	Vendor	Number	Vendor	Revision	Vendor	Organization				
	MT36HTS1G72F									15-May-		
Micron	Y-667A1D4	MT47H1G4THM-3:A	Micron	0467E	IDT	C1-667	FMHS	(1Gbx4)*18		08		
Crucial	CT102472AF667									15-May-		
Technology	.36DA1D4	MT47H1G4THM-3:A	Micron	0467E	IDT	C1-667	FMHS	(1Gbx4)*18		08		

**Note:** Some memory modules may have thermal issues when used in a non-Intel 1U rack solution. It is advised that you verify any thermal limitations with your chassis supplier before purchasing a chassis.

## 4. Intel<sup>®</sup> Carrier Grade Server TIGW1U SAS Front Panel Board Intel<sup>®</sup> RAID Cache Tested Memory

The following tables list Mini-DIMM devices tested to be compatible with the Intel<sup>®</sup> Carrier Grade Server TIGW1U SAS Front Panel board. The list of tested memory is periodically updated as qualified memory is added during the production life of the Intel product.

Intel strongly recommends the use of ECC memory in all server products.

Memory modules not listed in the following tables have not been tested for compatibility and their use as RAID cache in the SAS Front Panel Board subsystem with the Intel Carrier Grade Server TIGW1U may result in unpredictable operation and data loss.

# Mini-DIMMs used with the SAS Front Panel Board should be a single rank device (with at maximum nine x8 devices) due to the Intel<sup>®</sup> RAID Smart Battery (RSB) retention time requirements.

**Caution**: Third party memory vendors may use the same module part number with different DRAM vendors and die revisions. To insure proper system operation, verify that each DRAM vendor and die revision has been separately tested and qualified. Please notify CMTL if there is a discrepancy. This list is subject to change without notice.

**Note**: This list is not intended to be all-inclusive. It is provided as a convenience to Intel's general customer base, but Intel does not make any representations or warranties whatsoever regarding the quality, reliability, functionality, or compatibility of these memory modules.

	TIGW1U SAS Front Panel Board RAID Cache Registered ECC DDR Mini-DIMM Modules 128 MB Sizes											
Manufacturer Part Number Performance Rank DRAM # of Row/Bank Organization Compo- nents							Bank Address					
Micron	MT5HTF1672KY-40EB2	DDR2-400	1	32Mx16 (512Mb)	5	13/2/10	BA0-BA1					
Smart Modular Technologies	SG572163FG8RWDG	DDR2-533	1	16Mx16 (256Mb)	5	13/2/9	BA0-BA1					

	TIGW1U SAS Front Panel Board RAID Cache Registered ECC DDR Mini-DIMM Modules 256 MB Sizes										
Manufacturer	Manufacturer Part Number Performance Rank DRAM # of Row/Bank/ Bank Organization Compo- nents Column Addres										
Micron	MT5HTF3272KY-40ED1	DDR2-400	1	32Mx16 (512Mb)	5	13/2/10	BA0-BA1				
Smart Modular Technologies	SG572328FG8RWDB	DDR2-400	1	32Mx8 (256Mb)	9	13/2/10	BA0-BA1				

TIGW1U SAS Front Panel Board RAID Cache Registered ECC DDR Mini-DIMM Modules 512 MB Sizes							
Manufacturer	Part Number	Performance	Rank	DRAM	# of	Row/Bank/	Bank
				Organization	nents	Column	Address
Smart Modular Technologies	SG572648FG8RZDB	DDR2-400	1	64Mx8 (512Mb)	9	14/2/10	BA0-BA1
Micron	MT9HVF6472PKY- 53ED4	DDR2-533	1	64Mx8 (512Mb)	9	14/2/10	BA0-BA1
Micron	MT9HTF6472PKY- 53ED3	DDR2-533	1	64Mx16 (1Gb)	5	14/2/10	BA0-BA1

## 5. CMTL\* (Computer Memory Test Labs)

CMTL is a privately owned and operated memory testing organization responsible for testing a broad range of memory products. Memory devices tested by CMTL must undergo a rigorous battery of tests to ensure that the product will perform the intended server functions. Memory capability is a major factor your customers consider. CMTL has the ability to test and certify memory on Intel-based server platforms. The list of memory modules, which have undergone testing through the CMTL facility, should be referenced when considering modules for integration into this Intel server product. Stringent standards with regard to manufacturing procedures and quality must be met to pass the exacting tests required for qualification through the independent testing facility. Testing is performed by CMTL with Intel server products and test procedures defined by Intel's Memory Qualification Lab. Intel routinely audits the CMTL facility to ensure all procedures, process handling, and testing methodologies are met.

#### IMPORTANT NOTE

DIMM devices with gold contacts should NOT be placed into DIMM sockets with tin-lead contacts or viceversa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each Rank on the memory module. Mixing of dissimilar memory manufacturer devices or dissimilar memory device speeds is not recommended. This document contains information which is the proprietary property of Intel Corporation. Nothing in this document constitutes a guaranty, warranty, or license, express or implied. Intel has tested the following DIMMs for minimum electrical and functional compatibility with the Intel<sup>®</sup> Server RAID Controller. This listing is not intended to be all inclusive; it only represents the DIMMs Intel or CMTL has tested. Users of this list are reminded to check with the DIMM manufacturer or Distributor to ensure that a particular DIMM model is adequate for the intended purpose on the Intel<sup>®</sup> Server RAID Controller. Intel provides no indemnities for and expressly disclaims all liabilities for any and all such guaranties, representations, and warranties (oral or written) whether express or implied, related to DIMMs in a Intel<sup>®</sup> Server RAID Controller product, including without limitation to: fitness for a particular purpose; merchantability; noninfringement of intellectual property or other rights of any third party or of Intel. The reader is advised that third parties may have intellectual property rights which may be relevant to this document and the technologies discussed herein, and is advised to seek the advice of competent legal counsel, without obligation of Intel. Intel retains the right to make changes to this document at any time, without notice. Intel makes no warranty or representation with respect to the use of this document or reliance by the reader upon its contents, and assumes no responsibility for any errors which may appear in the document nor does it make a commitment to update the information contained herein.

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